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May 2014

# FQB27N25TM\_F085/FQI27N25TU\_F085

## N-Channel MOSFET

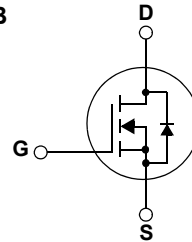
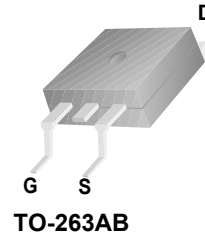
250 V, 25.5 A, 131 mΩ

### Features

- Typ  $R_{DS(on)}$  = 108mΩ at  $V_{GS}$  = 10V,  $I_D$  = 25.5A
- Typ  $Q_{g(tot)}$  = 45nC at  $V_{GS}$  = 10V,  $I_D$  = 27A
- UIS Capability
- RoHS Compliant
- Qualified to AEC Q101

### Applications

- Automotive Engine Control
- Powertrain Management
- Solenoid and Motor Drivers
- Electronic Steering
- Integrated Starter/Alternator
- Distributed Power Architectures and VRM
- Primary Switch for 12V Systems



For current package drawing, please refer to the Fairchild website at [www.fairchildsemi.com/packaging](http://www.fairchildsemi.com/packaging)

### MOSFET Maximum Ratings $T_J = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Ratings	Units
$V_{DSS}$	Drain to Source Voltage	250	V
$V_{GS}$	Gate to Source Voltage	±30	V
$I_D$	Drain Current - Continuous ( $V_{GS}=10$ ) (Note 1)	$T_C = 25^\circ\text{C}$	A
	Pulsed Drain Current	$T_C = 25^\circ\text{C}$	
$E_{AS}$	Single Pulse Avalanche Energy (Note 2)	972	mJ
$P_D$	Power Dissipation	417	W
	Derate above $25^\circ\text{C}$	3.3	W/ $^\circ\text{C}$
$T_J, T_{STG}$	Operating and Storage Temperature	-55 to + 150	$^\circ\text{C}$
$R_{\theta JC}$	Thermal Resistance, Junction to Case	0.3	$^\circ\text{C/W}$
$R_{\theta JA}$	Maximum Thermal Resistance, Junction to Ambient (Note 3)	43	$^\circ\text{C/W}$

### Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FQB27N25TM	FQB27N25TM_F085	TO-263AB	330mm	24mm	800 units
FQI27N25TU	FQI27N25TU_F085	TO-262AB	Tube	N/A	50 units

#### Notes:

- 1: Current is limited by bondwire configuration.
- 2: Starting  $T_J = 25^\circ\text{C}$ ,  $L = 4.67\text{mH}$ ,  $I_{AS} = 20.4\text{A}$ ,  $V_{DD} = 100\text{V}$  during inductor charging and  $V_{DD} = 0\text{V}$  during time in avalanche.
- 3:  $R_{\theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins.  $R_{\theta JC}$  is guaranteed by design while  $R_{\theta JA}$  is determined by the user's board design. The maximum rating presented here is based on mounting on a 1 in<sup>2</sup> pad of 2oz copper.

**Electrical Characteristics**  $T_J = 25^\circ\text{C}$  unless otherwise noted.

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
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**Off Characteristics**

$B_{V_{DS}}$	Drain to Source Breakdown Voltage	$I_D = 250\mu\text{A}$ , $V_{GS} = 0\text{V}$	250	-	-	V
$I_{DSS}$	Drain to Source Leakage Current	$V_{DS} = 250\text{V}$ , $T_J = 25^\circ\text{C}$ $V_{GS} = 0\text{V}$ , $T_J = 150^\circ\text{C}$ (Note 4)	-	-	1	$\mu\text{A}$
$I_{GSS}$	Gate to Source Leakage Current	$V_{GS} = \pm 30\text{V}$	-	-	$\pm 100$	nA

**On Characteristics**

$V_{GS(th)}$	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}$ , $I_D = 250\mu\text{A}$	3.0	4.1	5.0	V
$R_{DS(on)}$	Drain to Source On Resistance	$I_D = 25.5\text{A}$ , $T_J = 25^\circ\text{C}$ $V_{GS} = 10\text{V}$ , $T_J = 150^\circ\text{C}$ (Note 4)	-	108	131	$\text{m}\Omega$
			-	265	310	$\text{m}\Omega$

**Dynamic Characteristics**

C <sub>iSS</sub>	Input Capacitance	V <sub>DS</sub> = 25V, V <sub>GS</sub> = 0V, f = 1MHz		-	1800	-	pF
C <sub>oSS</sub>	Output Capacitance			-	350	-	pF
C <sub>rSS</sub>	Reverse Transfer Capacitance			-	45	-	pF
R <sub>g</sub>	Gate Resistance	f = 1MHz		-	0.82	-	Ω
Q <sub>g(ToT)</sub>	Total Gate Charge at 10V	V <sub>GS</sub> = 0 to 10V	V <sub>DD</sub> = 125V I <sub>D</sub> = 27A	-	45	49	nC
Q <sub>g(th)</sub>	Threshold Gate Charge	V <sub>GS</sub> = 0 to 2V		-	3.3	4	nC
Q <sub>gs</sub>	Gate to Source Gate Charge			-	12	-	nC
Q <sub>gd</sub>	Gate to Drain “Miller” Charge			-	23	-	nC

**Switching Characteristics**

$t_{on}$	Turn-On Time	$V_{DD} = 125\text{V}$ , $I_D = 27\text{A}$ , $V_{GS} = 10\text{V}$ , $R_{GEN} = 25\Omega$	-	-	196	ns
$t_{d(on)}$	Turn-On Delay		-	36	-	ns
$t_r$	Rise Time		-	122	-	ns
$t_{d(off)}$	Turn-Off Delay		-	81	-	ns
$t_f$	Fall Time		-	60	-	ns
$t_{off}$	Turn-Off Time		-	-	164	ns

**Drain-Source Diode Characteristics**

$V_{SD}$	Source to Drain Diode Voltage	$I_{SD} = 25.5\text{A}$ , $V_{GS} = 0\text{V}$	-	-	1.5	V
		$I_{SD} = 12.75\text{A}$ , $V_{GS} = 0\text{V}$	-	-	1.25	V
$t_{rr}$	Reverse--Recovery Time	$I_F = 27\text{A}$ , $dI_{SD}/dt = 100\text{A}/\mu\text{s}$	-	205	238	ns
$Q_{rr}$	Reverse--Recovery Charge	$V_{DD} = 200\text{V}$	-	1.8	2.3	nC

**Notes:**

4: The maximum value is specified by design at  $T_J = 150^\circ\text{C}$ . Product is not tested to this condition in production.

## Typical Characteristics

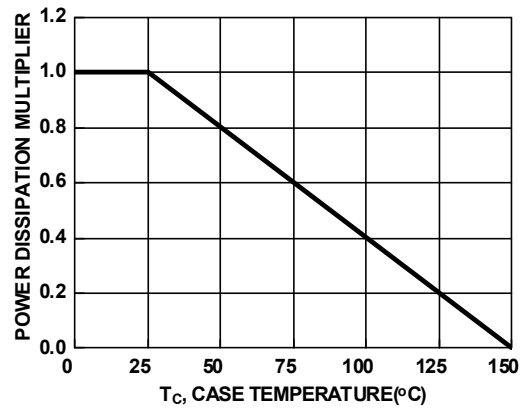


Figure 1. Normalized Power Dissipation vs. Case Temperature

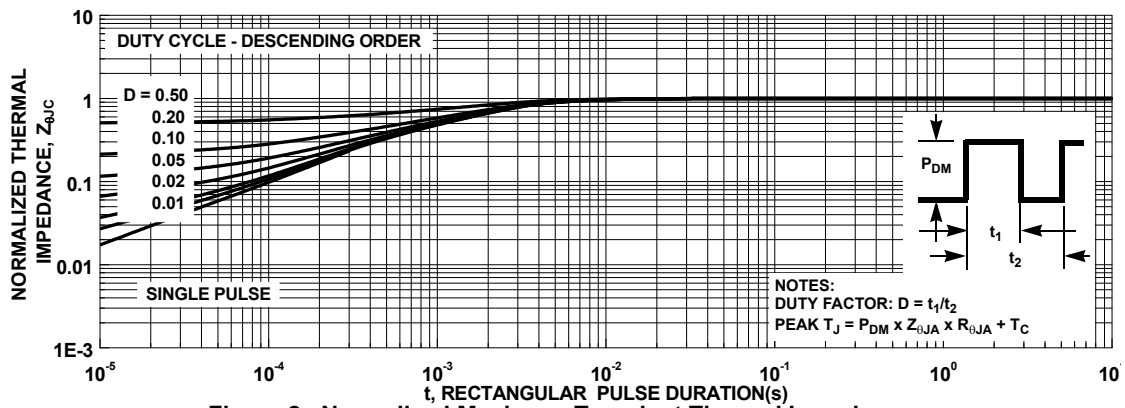


Figure 2. Normalized Maximum Transient Thermal Impedance

## Typical Characteristics

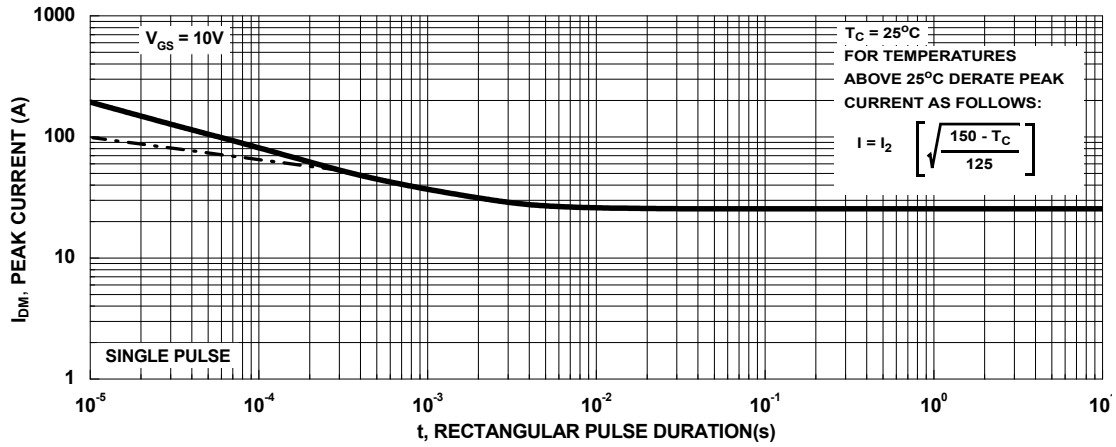


Figure 3. Peak Current Capability

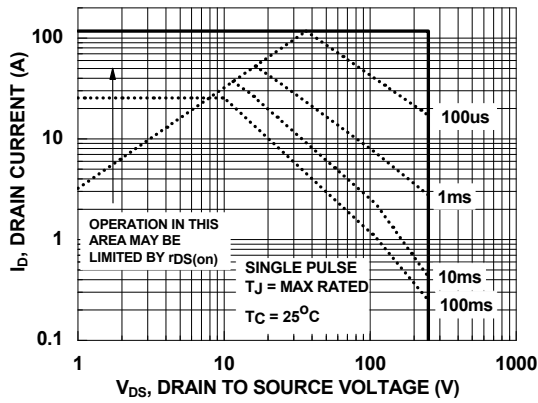
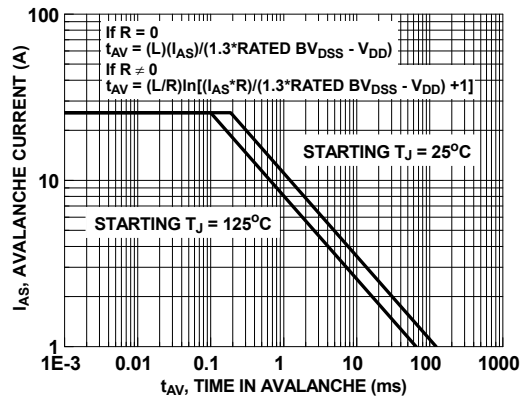


Figure 4. Forward Bias Safe Operating Area



NOTE: Refer to Fairchild Application Notes AN7514 and AN7515

Figure 5. Unclamped Inductive Switching Capability

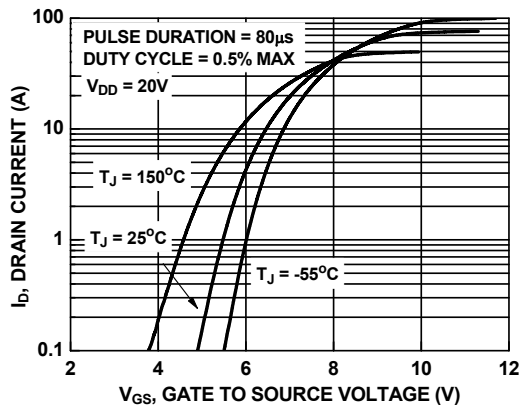


Figure 6. Transfer Characteristics

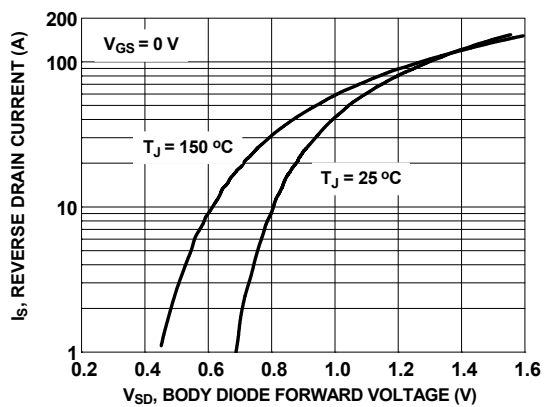


Figure 7. Forward Diode Characteristics

## Typical Characteristics

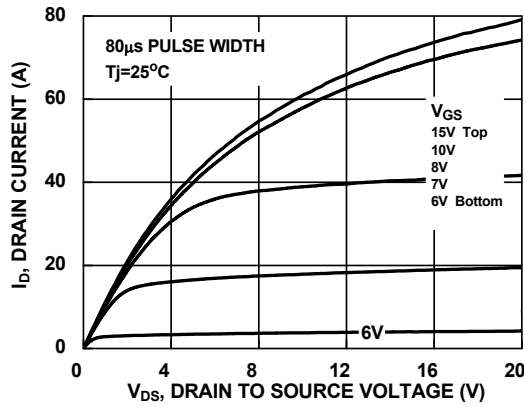


Figure 8. Saturation Characteristics

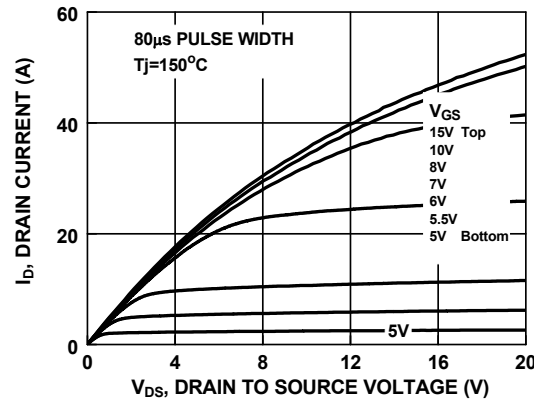


Figure 9. Saturation Characteristics

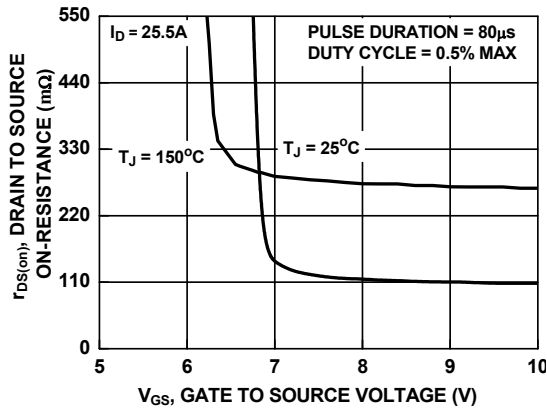


Figure 10. R<sub>DS(on)</sub> vs. Gate Voltage

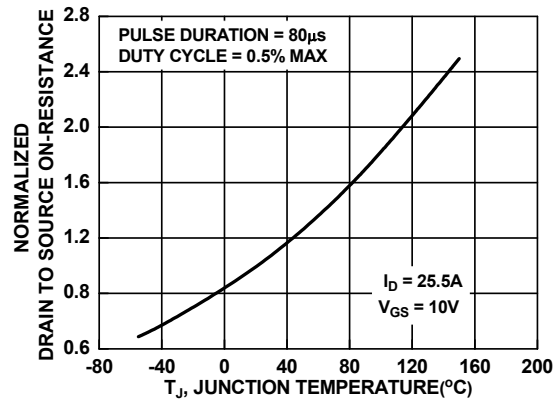


Figure 11. Normalized R<sub>DS(on)</sub> vs. Junction Temperature

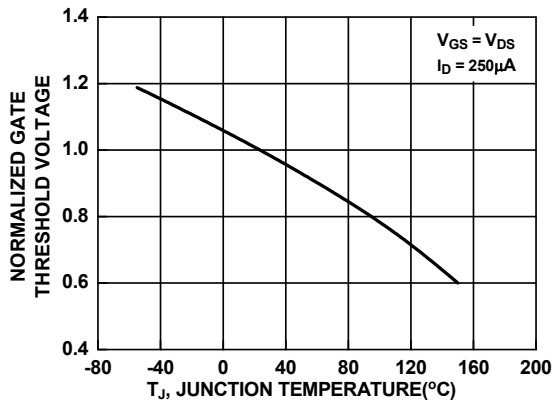


Figure 12. Normalized Gate Threshold Voltage vs. Temperature

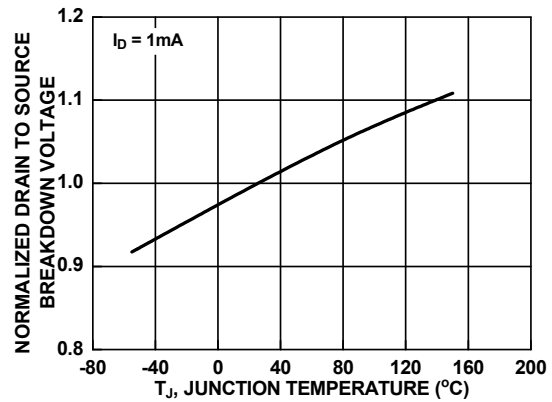


Figure 13. Normalized Drain to Source Breakdown Voltage vs. Junction Temperature

## Typical Characteristics

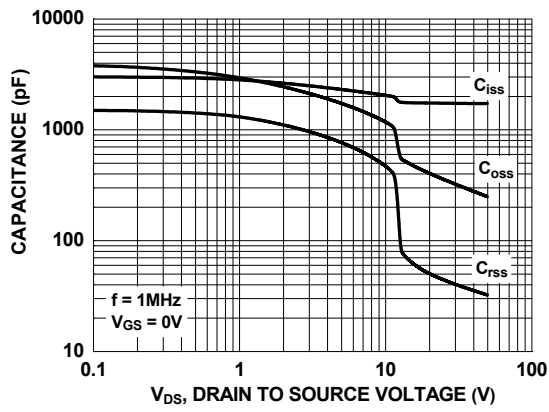


Figure 14. Capacitance vs. Drain to Source Voltage

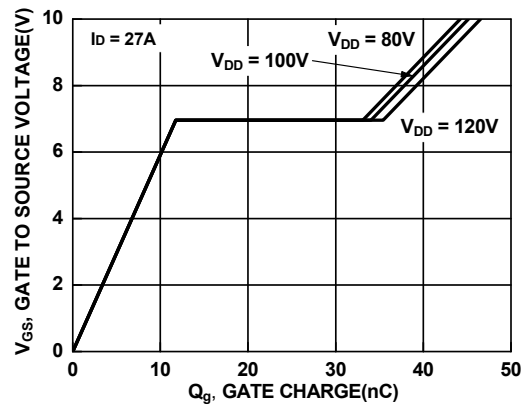



Figure 15. Gate Charge vs. Gate to Source Voltage





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